

Application No. 10/614,698
September 21, 2004
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Docket: P910190

Amendment to the Detailed Description

The paragraph bridging pages 23 and 24 has been amended to read as follows:

In certain embodiments, it may be desirable to form two opening matrices using two masks (or two orientations of a mask) such as illustrated in FIG. ~~10A and 10B~~ 11A and 11B, wherein in the illustrated embodiment one matrix comprising a plurality of vertical strip openings 70 and the other matrix comprising a plurality of horizontal strip openings 72. Such a process can include one or more strip openings in the first (and/or second) implantation resistant layer oriented in one direction, and one or more strip openings in the first (and/or second) implantation resistant layer oriented in another direction, such as ~~an~~ a direction orthogonal to the first strip openings. For example, an opening matrix may include first strip openings in an implantation resistant layer oriented in a first direction and second strip openings in the same implantation resistant layer oriented perpendicularly to the first strip openings. A plurality of vertical strip openings are formed in the first implantation resistant material, and then a plurality of horizontal strip openings are formed in the first implantation resistant material. The intersection of the strip openings thereby forms an opening matrix in the first implantation resistant material, as shown in FIG. 11C.